

L Number	Hits	Search Text	DB	Time stamp
1	3206	(257/314-326).CCLS.	USPAT; US-PGPUB	2003/12/01 16:13
2	243	((257/314-326).CCLS.) and @pd>20030622	USPAT; US-PGPUB	2003/12/01 16:14
3	129	(((((257/315,317,320).CCLS.)) and (ono oxide nitride)) and @pd>20030622	USPAT; US-PGPUB	2003/12/01 16:14
4	1063	floating adj gate and @pd>20030622	USPAT; US-PGPUB	2003/12/01 16:14
5	95	(floating adj gate) SAME thickness same (angstrom nanometer micron nm .mu) and @pd>20030622	USPAT; US-PGPUB	2003/12/01 16:14
6	19354	(flash floating-gate floating adj gate eeprom eeprom non-volatile) and @pd>20030622	USPAT; US-PGPUB	2003/12/01 16:15
7	2	(depressed depression angular angled) near4 (floating-gate floating adj gate) and @pd>20030622	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/01 16:16
8	1	726663.ap.	US-PGPUB	2003/12/01 16:16
9	1	347547.ap.	USPAT; US-PGPUB	2003/12/01 16:16
10	129	((((257/315,317,320).CCLS.)) and (ono oxide nitride) and @pd>20030622	USPAT; US-PGPUB	2003/12/01 16:16
11	10	((Lam and chung).in.) and @pd>20030622	USPAT; US-PGPUB	2003/12/01 16:17
12	1	("6225162").PN.	USPAT	2003/12/01 16:17
13	0	(Lam and Williams).in. and @pd>20030622	USPAT; US-PGPUB	2003/12/01 16:18